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IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In Re Application of : March 5, 2002
H.H. Chen, et al : Group Art No.: 2811
Serial No. 09/579,044 : Examiner: O. Nadav
Filed: May 26, 2000 : for IBM Corporation
Title: SEMICONDUCTOR HIGH
DIELECTRIC CONSTANT
DECOUPLING CAPACITOR
STRUCTURES AND PROCESS
FOR FABRICATION
3173 Cedar Road
Yorktown Heights, NY 10598

PRELIMINARY AMENDMENT

Commissioner for Patents
Washington, D.C. 20231

Sir:

This Preliminary Amendment is being filed simultaneously with the filing of a Continuation in Part Application. The Preliminary Amendment responds to the issues raised in the Final Office Action dated December 5, 2002.

Applicants wish to amend the Patent Application as follows: